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# Inclosure Material:

Ceramic and metal

**Overall Length:** 

0.235 inches

# **Overall Diameter:**

0.300 inches

# Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

### **Mounting Method:**

Threaded stud

### Features Provided:

Hermetically sealed case

### Thread Size:

# 0.164 inches

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter reverse voltage, with base short-circuited to emitter and 33.0 collector to emitter voltage/static/base open and 4.0

emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

1.00 amperes source cutoff current

# Power Rating Per Characteristic:

18.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### Test Data Document:

80063-sm-b-745775 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

### **Thread Series Designator:**

Unc

### **Terminal Type And Quantity:**

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

No

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